

Excellent Integrated System Limited

Stocking Distributor

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[Rohm Semiconductor](#)
[RB063L-30TE25](#)

For any questions, you can email us directly:

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Diodes

Schottky barrier diode

RB063L-30

● **Applications**

High frequency rectification
For switching power supply

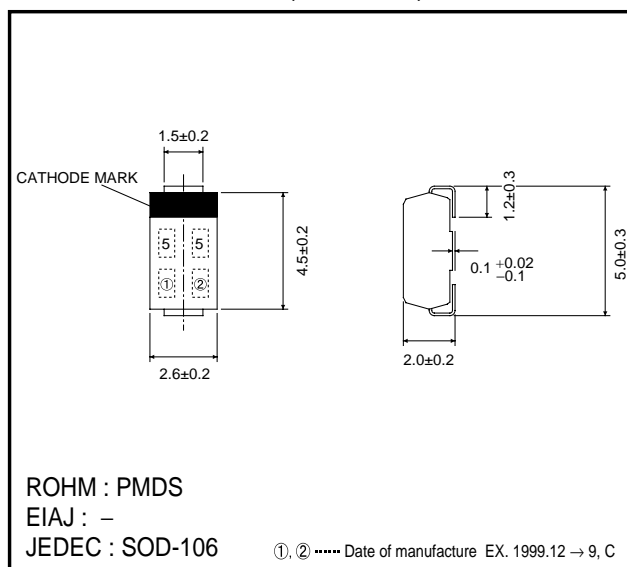
● **Features**

- 1) Compact power mold type. (PMDS)
- 2) Ultra low V_F / Low I_R .
- 3) $V_{RM}=30V$ guaranteed.

● **Construction**

Silicon epitaxial planar

● **External dimensions (Units : mm)**



● **Absolute maximum ratings ($T_a=25^\circ C$)**

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V_{RM}	30	V
DC reverse voltage	V_R	30	V
Mean rectifying current *	I_o	2	A
Peak forward surge current (60Hz·1 ϕ)	I_{FSM}	70	A
Junction temperature	T_J	125	$^\circ C$
Storage temperature	T_{stg}	-40~+125	$^\circ C$

* 180° half sine wave when mounted on glass epoxy PCBs.

● **Electrical characteristics ($T_a=25^\circ C$)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_F	-	-	0.395	V	$I_F=2.0A$
Reverse current	I_R	-	-	200	μA	$V_R=30V$

Diodes

● **Electrical characteristic curves (Ta=25°C)**

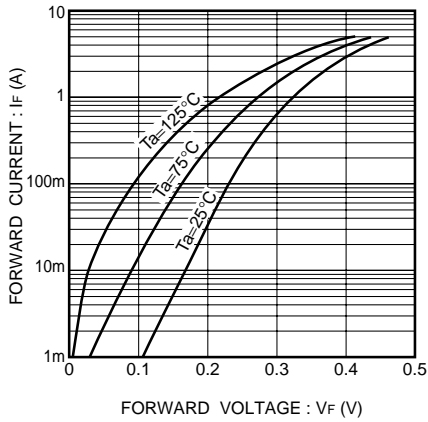


Fig.1 Forward characteristics

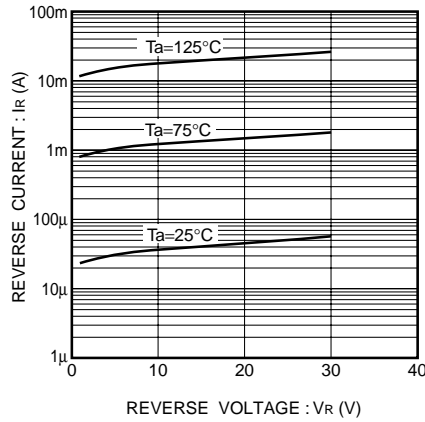


Fig.2 Reverse characteristics

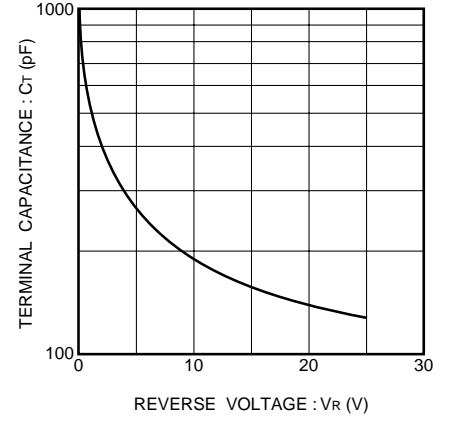


Fig.3 Capacitance between terminals characteristics

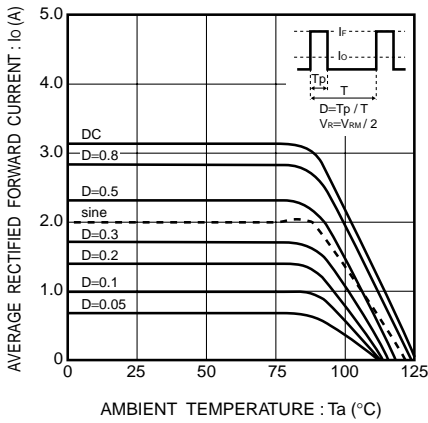


Fig.4 Derating curve (Io - Ta)
(When mounted on alumina PCBs)

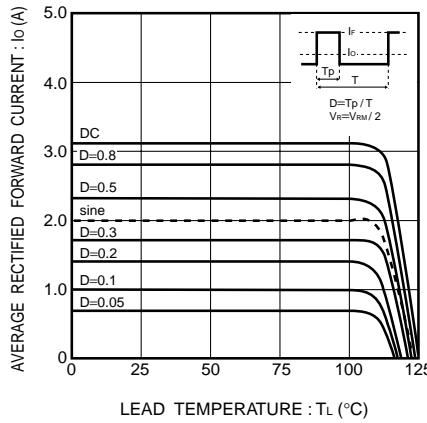


Fig.5 Derating curve (Io - Tl)
(When mounted on alumina PCBs)

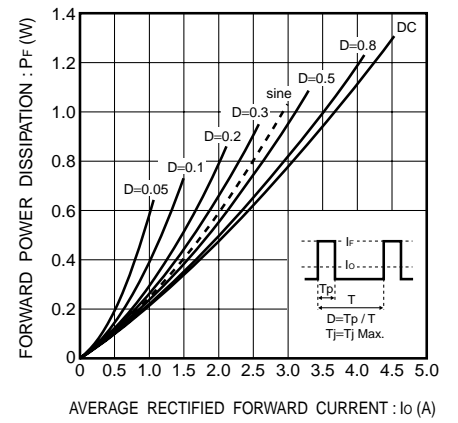


Fig.6 Forward power dissipation characteristics

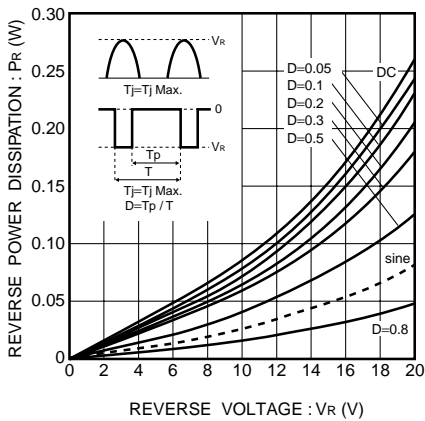


Fig.7 Reverse power dissipation characteristics

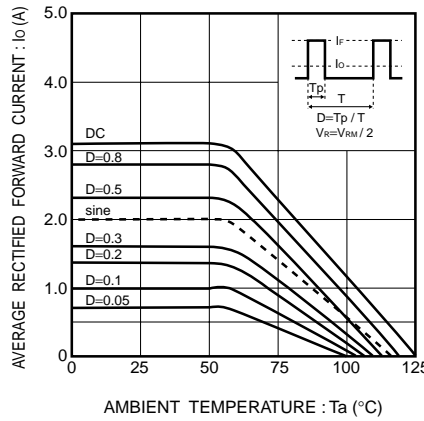


Fig.8 Derating curve (Io - Ta)
(when mounted on glass epoxy PCBs)